NSN 5961-00-104-0136

Demilitarization:

No Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-104-0136 **Inclosure Material:** Glass **Overall Length:** 0.085 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.065 inches **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 75.0 reverse voltage, instantaneous and 1.0 on voltage, forward voltage drop, dc **Current Rating Per Characteristic:** 200.00 milliamperes forward current, average and 150.00 milliamperes forward current, average absolute **Power Rating Per Characteristic:** 350.0 milliwatts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Precious Material And Location:** Terminal surface gold **Precious Material:** Gold **Test Data Document:** 94756-479-1084 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:**